

## 2N6236-2N6241

## SILICON CONTROLLED RECTIFIERS

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).

Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

### MAXIMUM RATINGS ( $T_C = 110^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
<b>Repetitive peak forward and reverse blocking voltage</b> <sup>(1)</sup> (1/2 sine wave, $R_{GK} = 1000\Omega$ , $T_C = -40$ to $+110^\circ\text{C}$ )	$V_{DRM}$ $V_{RRM}$	30	Volts
2N6236		50	
2N6237		100	
2N6238		200	
2N6239		400	
2N6240		600	
<b>Non-repetitive peak reverse blocking voltage</b> (1/2 sine wave, $R_{GK} = 1000\Omega$ , $T_C = -40$ to $+110^\circ\text{C}$ )	$V_{RSM}$	50	Volts
2N6236		100	
2N6237		150	
2N6238		250	
2N6239		450	
2N6240		650	
<b>Average on-state current</b> ( $T_C = -40$ to $+90^\circ\text{C}$ ) ( $T_C = 100^\circ\text{C}$ )	$I_{T(AV)}$	2.6	Amps
		1.6	
<b>Surge on-state current</b> (1/2 sine wave, 60Hz, $T_C = 90^\circ\text{C}$ ) (1/2 sine wave, 1.5ms, $T_C = 90^\circ\text{C}$ )	$I_{TSM}$	25	Amps
		35	
<b>Circuit fusing</b> ( $T_C = -40$ to $+110^\circ\text{C}$ , $t = 8.3\text{ms}$ )	$I^2t$	2.6	$\text{A}^2\text{s}$
<b>Peak gate power</b> (pulse width = $10\mu\text{s}$ , $T_C = 90^\circ\text{C}$ )	$P_{GM}$	0.5	Watts
<b>Average gate power</b> ( $t = 8.3\text{ms}$ , $T_C = 90^\circ\text{C}$ )	$P_{G(AV)}$	0.1	Watts
<b>Peak forward gate current</b>	$I_{GM}$	0.2	Amps
<b>Peak reverse gate voltage</b>	$V_{RGM}$	6	Volts
<b>Operating junction temperature range</b>	$T_J$	-40 to 110	$^\circ\text{C}$
<b>Storage temperature range</b>	$T_{stg}$	-40 to 150	$^\circ\text{C}$
<b>Stud torque</b>		6	In. lb.

Note 1: Ratings apply for zero or negative gate voltage. Devices shall not have a positive bias applied to the gate concurrently with a negative potential on the anode. Devices should not be tested with a constant source for forward or reverse blocking capability such that the voltage applied exceeds the rated blocking voltage.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal resistance, junction to case	$R_{\theta JC}$	3	$^\circ\text{C}/\text{W}$
Thermal resistance, junction to ambient	$R_{\theta JA}$	75	$^\circ\text{C}/\text{W}$

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ , $R_{GK} = 1000\Omega$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>Peak forward or reverse blocking current</b> (Rated $V_{DRM}$ or $V_{RRM}$ ) $T_C = 25^\circ\text{C}$ $T_C = 110^\circ\text{C}$	$I_{DRM}$ $I_{RRM}$	-	-	10	$\mu\text{A}$
		-	-	200	
<b>Peak forward "on" voltage</b> ( $I_{TM} = 8.2\text{A}$ peak, pulse width = 1 to 2ms, 2% duty cycle)	$V_{TM}$	-	-	2.2	Volts

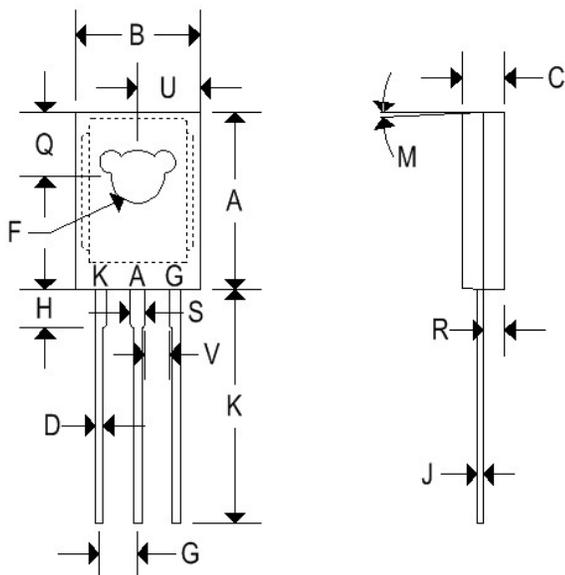
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## SILICON CONTROLLED RECTIFIERS

Characteristic	Symbol	Min	Typ	Max	Unit
<b>Gate trigger current (continuous dc)</b> ( $V_{AK} = 12\text{Vdc}$ , $R_L = 24\Omega$ ) ( $V_{AK} = 12\text{Vdc}$ , $R_L = 24\Omega$ , $T_C = -40^\circ\text{C}$ )	$I_{GT}$	-	-	200 500	$\mu\text{A}$
<b>Gate trigger voltage (continuous dc)</b> (Source voltage = 12V, $R_S = 50\Omega$ ) ( $V_{AK} = 12\text{Vdc}$ , $R_L = 24\Omega$ , $T_C = -40^\circ\text{C}$ )	$V_{GT}$	-	-	1	Volts
<b>Gate non-trigger voltage</b> ( $V_{AK} = \text{rated } V_{DRM}$ , $R_L = 100\Omega$ , $T_C = 110^\circ\text{C}$ )	$V_{GD}$	0.2	-	-	Volts
<b>Holding current</b> ( $V_{AK} = 12\text{Vdc}$ , $I_{GT} = 2\text{mA}$ ) (initiating on state current = 200mA) $T_C = 25^\circ\text{C}$ $T_C = -40^\circ\text{C}$	$I_H$	-	-	5 10	mA
<b>Total turn-on time</b> (Source voltage = 12V, $R_S = 6\text{k}\Omega$ ) ( $I_{TM} = 8.2\text{A}$ , $I_{GT} = 2\text{mA}$ , rated $V_{DRM}$ ) (Rise time = 20ns, pulse width = 10 $\mu\text{s}$ )	$t_{gt}$	-	-	2	$\mu\text{s}$
<b>Forward voltage application rate</b> ( $V_D = \text{Rated } V_{DRM}$ , $T_C = 110^\circ\text{C}$ )	dv/dt	-	10	-	V/ $\mu\text{s}$

### MECHANICAL CHARACTERISTICS

Case	TO-126
Marking	Alpha-numeric
Pin out	See below



	TO-126			
	Inches		Millimeters	
	Min	Max	Min	Max
A	0.425	0.435	10.80	11.050
B	0.295	0.305	7.490	7.750
C	0.095	0.105	2.410	2.670
D	0.020	0.026	0.510	0.660
F	0.115	0.125	2.920	3.180
G	0.091	0.097	2.310	2.460
H	0.050	0.095	1.270	2.410
J	0.015	0.025	0.380	0.640
K	0.595	0.655	15.110	16.640
M	3° TYP		3° TYP	
Q	0.148	0.158	3.760	4.010
R	0.045	0.055	1.140	1.400
S	0.025	0.035	0.640	0.890
U	0.145	0.155	3.680	3.940
V	0.040	-	1.020	-

FIGURE 1 – MAXIMUM CASE TEMPERATURE

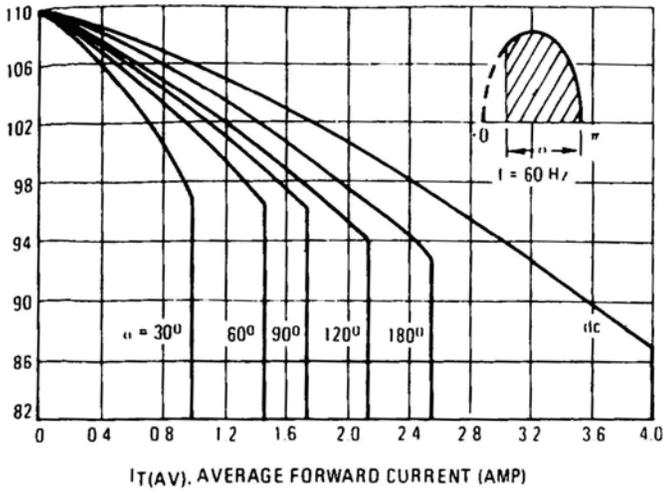


FIGURE 2 – MAXIMUM AMBIENT TEMPERATURE

